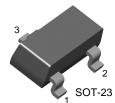
FAIRCHILD

SEMICONDUCTOR®

KST5179

RF Amplifier Transistor



KST5179

NPN Epitaxial Silicon Transistor

Absolute Maximum Ratings $T_a=25$ °C unless otherwise noted

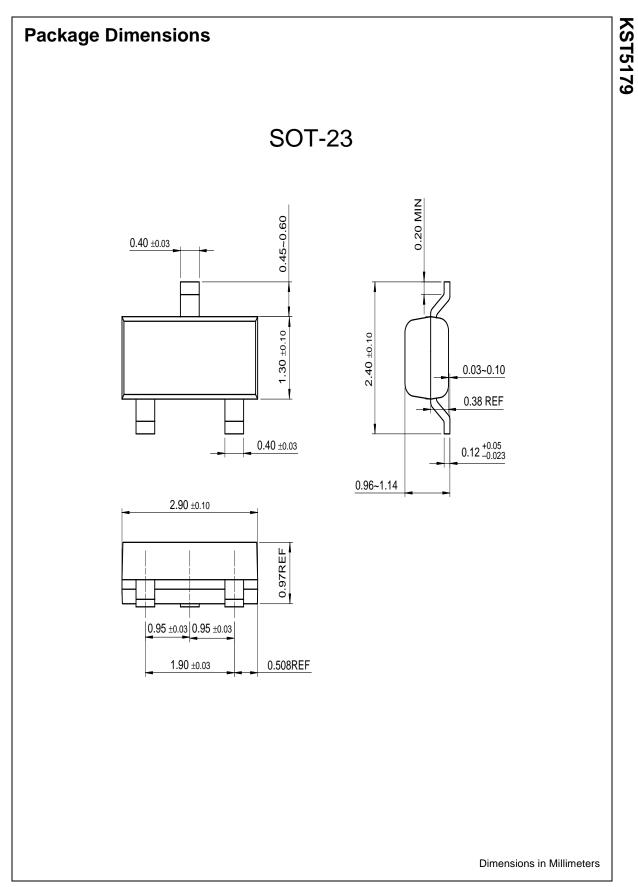
Symbol	Parameter	Value	Units
V _{CBO}	Collector-Base Voltage	20	V
V _{CEO}	Collector-Emitter Voltage	12	V
V _{EBO}	Emitter-Base Voltage	2.5	V
I _C	Collector Current	50	mA
P _C	Collector Power Dissipation (T _a =25°C)	350	mW
	Derate above 25°C	2.8	mW/°C
TJ	Junction Temperature	150	°C
T _{STG}	Storage Temperature	-55 ~ 150	°C

Electrical Characteristics $T_a=25^{\circ}C$ unless otherwise noted

Symbol	Parameter	Test Condition	Min.	Max.	Units	
BV _{CBO}	Collector-Base Breakdown Voltage	I _C =0.01mA, I _E =0	20		V	
BV _{CEO}	Collector-Emitter Breakdown Voltage	I _C =3mA, I _B =0	12		V	
BV _{EBO}	Emitter Base Breakdown Voltage	I _E =0.01mA, I _C =0	2.5		V	
I _{CBO}	Collector Cut-off Current	V _{CB} =15V, I _E =0		0.02	μΑ	
h _{FE}	DC Current Gain	V _{CE} =1V, I _C =3mA	25			
V _{CE} (sat)	Collector-Emitter Saturation Voltage	I _C =10mA, I _B =1mA		0.4	V	
V _{BE} (sat)	Base-Emitter Saturation Voltage	I _C =10mA, I _B =1mA		1	V	
f _T	Current Gain Bandwidth Product	V _{CE} =6V, I _C =5mA, f=100MHz	900		MHz	
C _{ob}	Output Capacitance	V_{CB} =10V, I _E =0, f=0.1MHz to 1MHz		1	pF	
h _{fe}	Small Signal Current Gain	V _{CE} =6V, I _C =2mA, f=1KHz	25			
NF	Noise Figure	V_{CE} =6V, I _C =1.5mA, f=200MHz R _S =50 Ω		4.5	dB	
G _{PE}	Power Gain	V _{CE} =6V, I _C =5mA, f=200MHz	15		dB	



1. Base 2. Emitter 3. Collector



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2. A critical component is any component of a life support device or system whose failure to perform can be reasonably expected to cause the failure of the life support device or system, or to affect its safety or effectiveness.

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Definition of Terms

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No Identification Needed	Full Production	This datasheet contains final specifications. Fairchild Semiconductor reserves the right to make changes at any time without notice in order to improve design.
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